
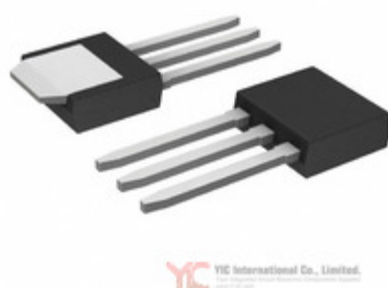

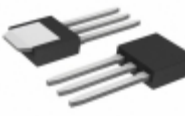



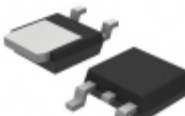

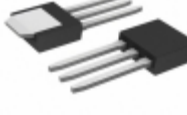
	<p><b>NTD24N06-1G</b></p>
	<p><b>Hersteller-Teilenummer:</b> NTD24N06-1G</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 24A IPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD24N06-1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 5000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NTD24N06-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 24A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.36W (Ta), 62.5W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	24A (Ta)
Rds On (Max) @ Id, Vgs	42 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	48nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1200pF @ 25V
Verpackung	Tube

NTD24N06-1G ist neu im Original, Suche NTD24N06-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD24N06-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD24N06-1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTD2425-10</b> Crydom RELAY SSR AC OUT 240VAC 25A PNL</p>	 <p><b>NTD24N06L-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A IPAK</p>	 <p><b>NTD2410F</b> Crydom RELAY SSR AC OUT 240VAC 10A PNL</p>	 <p><b>NTD2425</b> Crydom RELAY SSR AC OUT 240VAC 25A PNL</p>
 <p><b>NTD24N06-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A IPAK</p>	 <p><b>NTD24N06G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A DPAK</p>	 <p><b>NTD24N06L4T</b> O NTD24N06L4T O</p>	 <p><b>NTD24N06L-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 24A IPAK</p>

### heiße Teile

Mehr

 NTD20N06HL	 NTD20N06L	 NTD20N06L-001	 NTD20N06L-1G	 NTD20N06LG
 NTD20N06LT4	 NTD20N06LT4G	 NTD20N06T4G	 NTD20N06V	 NTD20P03
 NTD20P03HDLT4G	 NTD20P06HCT4G	 NTD20P06HD	 NTD20P06HDLT4	 NTD20P06HL
 NTD20P06L	 NTD20P06L-001	 NTD20P06LG	 NTD20P06LT4G	 NTD23N03R-1
 NTD23N03R-1G	 NTD23N03RG	 NTD23N03RT4	 NTD23N03RT4G	 NTD24N06
 NTD24N06G	 NTD24N06L	 NTD24N06L-001	 NTD24N06L-1G	 NTD24N06L4T
 NTD24N06LG	 NTD24N06LT4	 NTD24N06LT4G	 NTD24N06T4	 NTD24N06T4G
 NTD25N06HL	 NTD25P03	 NTD25P03L	 NTD25P03L-1	 NTD25P03L1G
 NTD25P03LG	 NTD25P03LRLG	 NTD25P03LT4G	 NTD25P06LT4G	 NTD2955-001
 NTD2955-1	 NTD2955-1G	 NTD2955D	 NTD2955E	 NTD2955G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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